INFORMATION DISCLOSURE CITATION

ATTY. DOCKET NO.
4105-17
APPLICANT

NO. OTATA PARAMETERS

SERIAL NO. 10/615,403

ONOE et al.

(Use several sheets if necessary)

FILING DATE

July 9, 2003

TC/A.U. 2627

U.S. PATENT DOCUMENTS

*EXAMINER							ING DATE	
INITIAL /KB/T	2007/0014047	DATE 01/2007	NAME Cho et al.	CLASS	SUBCLASS	IF AF	PROPRIA	Ŧ
	2006/0219655	11/2006	Cho et al.	-		-		╁
-	2006/0245312	11/2006	Maeda et al.		ļ	-		Ͱ
-	2006/0182004	08/2006	Maeda et al.			-		Н
	2004/0263185	12/2004	Cho et al.	324	636	-		_
	2004/0203183	06/2004	Kume	386	125	-		_
-	2004/0114913	03/2003				-		_
\rightarrow			Cho et al.	369	126			_
	2004/0027935	02/2004	Cho et al.	369	126	_		
	2003/0021213	01/2003	Hagiwara, Yoshiaki	369	101	_		
	2,872,529	02/1959	Hollmann et al.					
	4,320,491	03/1982	Rustman, James C.	369	126			
	4,455,638	06/1984	Wilson	369	126			
	4,489,278	12/1984	Sawazaki, Norikazu	324	457			
	5,418,029	05/1995	Yamamoto et al.	428	64.2			
	5,481,527	01/1996	Kasanuki et al.	369	126			
	5,646,932	07/1997	Kuribayashi et al.	369	126			
	5,751,685	05/1998	Yi, You-Wen	369	126		7	
	5,777,977	07/1998	Fujiwara et al.	369	126		T	Τ
	5,581,537	12/1996	Yamano et al.	369	126		T	_
	5,914,920	06/1999	Yokogawa	369	275.3		1	
	5,946,284	08/1999	Chung et al.	369	126		7	_
	6,477,132	11/2002	Azuma et al.	369	126			
	6,510,130	01/2003	Hayashi et al.	369	275.3			
	6,515,957	02/2003	Newns et al.	369	126		 	_
	6,653,630	11/2003	Rosenman et al.	250	306			_
	6,762,402	07/2004	Choi et al.	250	234			_
	6,841,220	01/2005	Onoe et al.	428	66.7	1		_
	6,912,193	06/2005	Cho et al.	369	126	1		
	6,965,545	11/2005	Hino et al.	369	13.54	1		_
	7,065,033	06/2006	Onoe et al.	369	126	\top		_
/KB/	7,149,180	12/2006	Onoe et al.	369	276	1		_

FOREIGN PATENT DOCUMENTS

	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANSL YES	ATION NO
/KB/	2003085969	03/2003	JP			ABSTRACT	
/KB/	08-075806	03/1996	JP			ABSTRACT	
/KB/	644 426 A	10/1950	GB				
/KB/	10-334525	12/1998	JP		1	ABSTRACT	
/KB/	56-107338	08/1981	JP			ABSTRACT	
*Examiner	/Kevin	Bernatz/	Date Considered	06/06/200)8		

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

meet & or 4			
INFORMATION DISCLOSURE	ATTY. DOCKET NO.	SERIAL NO.	
CITATION	4105-17	10/615,403	
	APPLICANT		
	ONOE et al.		
(Use several sheets if necessary)	FILING DATE	TC/A.U.	
	July 9, 2003	2627	

OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)

62th Japan Society of Applied Physics Lecture Meeting (2001.9 Aichi Institute of Technology) 12p-ZR-2.

XAMINER			U.S. PATENT DOCUMENTS			FILING	DATE
INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	IF APPR	OPRATI
/KB/	5,488,602	01/1996	Yamano et al.	369	126		\neg
	5,808,977	09/1998	Koyanagi et al.	369	127		\neg
	6,001,519	12/1999	Yang et al.				T
	6,096,434	08/2000	Yano et al.				T
	6,197,989	03/2001	Furukawa et al.	556	450		7
	6,942,914	09/2005	Onoe et al.				T
	7,212,484	05/2007	Maeda et al.				1
	7,242,661	07/2007	Cho et al.				
	7,227,830	6/2007	Cho et al.				
	7,221,639	05/2007	Onoe et al:				
	7,218,600	05/2007	Cho et al.				
	7,151,739	12/2006	Cho et al.				
	2005/0122886	06/2005	Takahashi et al.	369	126		
	2005/0099895	05/2005	Maeda et al.	369	13.01		
	2005/0098532	05/2005	Onoe et al.	216	22		
	20050047288	03/2005	Maeda et al.	369	53.25		
	2004/0252621	12/2004	Cho et al.	369	126		
	2004/0105380	06/2004	Cho et al.	369	126		
	2004/0105373	06/2004	Maeda et al.	369	101	\neg	
	2004/0090903	05/2004	Cho et al.	369	126		
	2004/0042351	03/2004	Onoe et al.	369	13.01		
	2002/0131669	09/2002	Onoe et al.	385	14	7	
	2002/0118906	08/2002	Onoe	385	14	7	
	2002/0105249	08/2002	Yoshida et al.	310	311	1	
/KB/	2003/0186090	10/2003	Onoe et al.			1	

FOREIGN PATENT DOCUMENTS

TRANSLATION DOCUMENT DATE COUNTRY CLASS SUBCLASS YES /KB/ 1 484 256 09/1977 GB /KB/ 0 739 004 11/1996 EP 11/2001 /KB/ 1 154 422 EP

	/Kevin Bernatz/	ı	06/06/2008
*Examiner		Date Considered	

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

INFORMATION DISCLOSURE	ATTY. DOCKET NO.	SERIAL NO.	
CITATION	4105-17	10/615,403	
	APPLICANT		
	ONOE et al.		
(Use several sheets if necessary)	FILING DATE	TC/A.U.	
*	July 9, 2003	2627	

	OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)
/KB/	Kazuta et al, "Determination of crystal polarities of piezoelectric thin film using scanning nonlinear dielectric
77100	microscopy", Journal of European Ceramic Society 21 (2001) 1581-1584.
/KB/	The Institution of Electrical Engineers, Stevenage, GB; 1 June 2002; Hiranaga et al, "Nano-sized inverted domain
	formation in stoichiometric LiTaO/sub3/single crystal using Scanning Nonlinear Dielectric Microscopy", XP002292217.
#CD/	Cho et al, "Scanning nonlinear dielectric microscopy with nanometer resolution", Journal of European Ceramic Society
/KB/	21 (2001) 2131-2134.
/KB/	Cho et al., "Nano domain engineering using scanning nonlinear dielectric microscopy, October 29, 2001, IEE-NANO
/ND/	2001, pages 352-357.

06/06/2008 /Kevin Bernatz/ *Examiner Date Considered

INFORMATION DISCLOSURE

CITATION

Atty. Docket No.

Serial No. 10/615.403

4105-17 Applicant

ONOE, A. et

TC/A.U.

(Use several sheets if necessary)

July 9, 2003 2627

		U.S	. PATENT DOCUMENTS		
*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	FILING DATE SUBCLASS IF APPROPRIATE
/KB/	6,606,726 B1	8/2003	Wilhelmsson et al		
/KB/	5,635,037	06/1997	Chu et al.		
/KB/	6,249,503	6/2001	Aratani		
/KB/	6,272,083	8/2001	Aratani		
/KB/ -/KB/	5,490,132	2/1996	Yagi et al.		
	5,412,641	5/1995	Shinjo et al.		
7KB/	5,047,649	9/1991	Hodgson et al.		
					/
					1

FOREIGN PATENT DOCUMENTS

DATE 12/1982	COUNTRY	CLASS			
12/1982			SUBCLASS	YES	NO
	JP			ABSTRACT	
12/2001	WO				
12/1995	JP		7	ABSTRACT	
6/2000	WO		/		
1/2004	EP				
11/1997	JP			ABSTRACT	
7/1999	JP			ABSTRACT	_
4/1992	EP				
8/1997	JP			ABSTRACT	
2/1984	JP			ABSTRACT	
	2/1984	2/1984 JP	2/1984 JP	2000	2/1984 JP ABSTRACT

	OTTIER DOCUMENTO (including Additor, Title, Date, Fertilient pages, etc.)						
/KB/		Cho et al, "Tbit/inch2 ferroelectric data storage based on scanning nonlinear dielectric microscopy", Applied Physics					
		Letters, Vol. 81, No. 23, December 2, 2002, pages 4401-4403.					
	Г						
	-						
	Ц.						

*Examiner	/Kevin Bernatz/	Date Considered	06/06/2008				
Evaminary leiting of reference general and the state of t							